

گروه فنی مهندسی جوش و برش مقدم

اعتماد از شما کیفیت و تخصص از ما



09153223758



051-37581400



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مشهد خیام شمالی 63 خیابان پردیس 3



- 7 سال سابقه آموزش تعمیرات تخصصی دستگاه های جوش اینورتری تک فاز و 3 فاز
- 7 سال سابقه فروش قطعات الکترونیکی دستگاه جوش
 تک فاز و 3 فاز
- آموزش تخصصی تحلیل دستگاه های جوش اینورتری مختص ابراز فروشان
 - آموزش تخصصی ابراز آلات شارژی



KSE13001



Color TV Chroma Output

- Collector-Base Voltage : V_{CBO}=400V
- Current Gain Bandwidth Product : f_T=50MHz (TYP.)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	400	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	7	V
I _C	Collector Current	100	mA
P _C	Collector Dissipation	600	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ +150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C =100μA, I _E =0	400			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C=5mA$, $I_B=0$	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =100μA, I _C =0	7			V
I _{CBO}	Collector Cut-off Current	V _{CB} =200V, I _E =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =10V, I _C =20mA	40		80	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =10mA, I _B =1mA			0.5	V
f _T	Current Gain Bandwidth Product	V_{CE} =30V, I_{C} =10mA		50		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		4		pF

h_{FE} Classification

Classification	R	0	
h _{FE}	40 ~ 65	55 ~ 80	

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Typical Characteristics

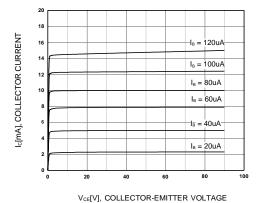


Figure 1. Static Characteristic

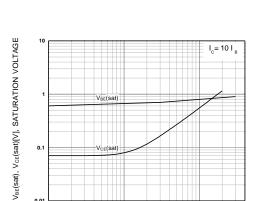
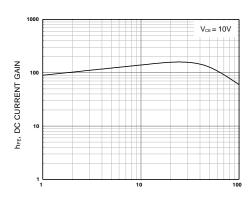


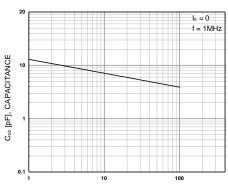
Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

Ic[mA], COLLECTOR CURRENT



Ic[mA], COLLECTOR CURRENT

Figure 2. DC current Gain



V_{CB}[V], COLLECTOR-BASE VOLTAGE

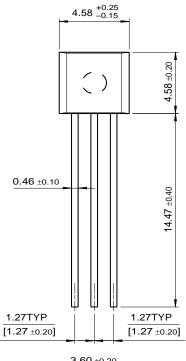
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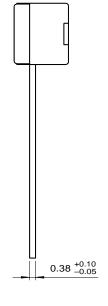
Figure 4. Collector Output Capacitance

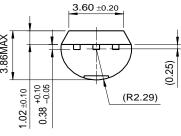
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Package Demensions

TO-92







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